

# MAC997 Series

Preferred Device

## Sensitive Gate Triacs

### Silicon Bidirectional Thyristors

Designed for use in solid state relays, MPU interface, TTL logic and any other light industrial or consumer application. Supplied in an inexpensive TO-92 package which is readily adaptable for use in automatic insertion equipment.

- One-Piece, Injection-Molded Package
- Blocking Voltage to 600 Volts
- Sensitive Gate Triggering in Four Trigger Modes (Quadrants) for all possible Combinations of Trigger Sources, and especially for Circuits that Source Gate Drives
- All Diffused and Glassivated Junctions for Maximum Uniformity of Parameters and Reliability
- Improved Noise Immunity (dv/dt Minimum of 20 V/ $\mu$ sec at 110°C)
- Commutating di/dt of 1.6 Amps/msec at 110°C
- High Surge Current of 8 Amps
- Device Marking: Device Type, e.g., for MAC997A6: MAC7A6, Date Code
- **These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at [www.onsemi.com](http://www.onsemi.com) for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.**

**MAXIMUM RATINGS** ( $T_J = 25^\circ\text{C}$  unless otherwise noted)

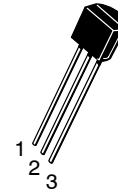
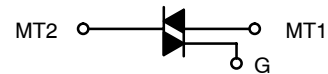
Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage ( $T_J = -40$ to $+110^\circ\text{C}$ ) <sup>(1)</sup> Sine Wave 50 to 60 Hz, Gate Open MAC997A6,B6 MAC997A8,B8	$V_{\text{DRM}}$ , $V_{\text{RRM}}$	400 600	Volts
On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz ( $T_C = +50^\circ\text{C}$ )	$I_{\text{T(RMS)}}$	0.8	Amp
Peak Non-Repetitive Surge Current One Full Cycle, Sine Wave 60 Hz ( $T_C = 110^\circ\text{C}$ )	$I_{\text{TSM}}$	8.0	Amps
Circuit Fusing Considerations ( $t = 8.3$ ms)	$I^2t$	.26	$\text{A}^2\text{s}$
Peak Gate Voltage ( $t \leq 2.0$ $\mu\text{s}$ , $T_C = +80^\circ\text{C}$ )	$V_{\text{GM}}$	5.0	Volts
Peak Gate Power ( $t \leq 2.0$ $\mu\text{s}$ , $T_C = +80^\circ\text{C}$ )	$P_{\text{GM}}$	5.0	Watts
Average Gate Power ( $T_C = 80^\circ\text{C}$ , $t \leq 8.3$ ms)	$P_{\text{G(AV)}}$	0.1	Watt
Peak Gate Current ( $t \leq 2.0$ $\mu\text{s}$ , $T_C = +80^\circ\text{C}$ )	$I_{\text{GM}}$	1.0	Amp
Operating Junction Temperature Range	$T_J$	-40 to +110	$^\circ\text{C}$
Storage Temperature Range	$T_{\text{stg}}$	-40 to +150	$^\circ\text{C}$



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**TRIACS**  
**0.8 AMPERE RMS**  
**400 thru 600 VOLTS**



**TO-92 (TO-226AA)**  
**CASE 029**  
**STYLE 12**

PIN ASSIGNMENT	
1	Main Terminal 1
2	Gate
3	Main Terminal 2

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

## MAC997 Series

(1)  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

### Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	75	$^{\circ}C/W$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^{\circ}C/W$
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	$T_L$	260	$^{\circ}C$

### Electrical Characteristics ( $T_C = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
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### Off Characteristics

Peak Repetitive Blocking Current ( $V_D = \text{Rated } V_{DRM}, V_{RRM}; \text{ Gate Open}$ )	$I_{DRM}, I_{RRM}$	—	—	10	$\mu A$
$T_J = 25^{\circ}C$		—	—	100	$\mu A$
$T_J = +110^{\circ}C$		—	—		

### On Characteristics

Peak On-State Voltage ( $I_{TM} = \pm .85 \text{ A Peak}; \text{ Pulse Width } \leq 2.0 \text{ ms}, \text{ Duty Cycle } \leq 2.0\%$ )	$V_{TM}$	—	—	1.9	Volts
Gate Trigger Current (Continuous dc) ( $V_D = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}$ )	$I_{GT}$				mA
MT2(+), G(+) MAC997A6,A8		—	—	5.0	
MT2(+), G(-)		—	—	5.0	
MT2(-), G(-)		—	—	5.0	
MT2(-), G(+)		—	—	7.0	
MT2(+), G(+) MAC997B6,B8		—	—	3.0	
MT2(+), G(-)		—	—	3.0	
MT2(-), G(-)		—	—	3.0	
MT2(-), G(+)		—	—	5.0	
Latching Current ( $V_D = 12 \text{ V}, I_G = 10 \text{ mA}$ )	$I_L$				mA
MT2(+), G(+) All Types		—	1.6	15	
MT2(+), G(-) All Types		—	10.5	20	
MT2(-), G(-) All Types		—	1.5	15	
MT2(-), G(+) All Types		—	2.5	15	
Gate Trigger Voltage (Continuous dc) ( $V_D = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}$ )	$V_{GT}$				Volts
MT2(+), G(+) All Types		—	.66	2.0	
MT2(+), G(-) All Types		—	.77	2.0	
MT2(-), G(-) All Types		—	.84	2.0	
MT2(-), G(+) All Types		—	.88	2.5	
Gate Non-Trigger Voltage ( $V_D = 12 \text{ V}, R_L = 100 \text{ Ohms}, T_J = 110^{\circ}C$ ) All Four Quadrants	$V_{GD}$	0.1	—	—	Volts
Holding Current ( $V_D = 12 \text{ Vdc}, \text{ Initiating Current} = 200 \text{ mA}, \text{ Gate Open}$ )	$I_H$	—	1.5	10	mA
Turn-On Time ( $V_D = \text{Rated } V_{DRM}, I_{TM} = 1.0 \text{ A pk}, I_G = 25 \text{ mA}$ )	$t_{gt}$	—	2.0	—	$\mu s$

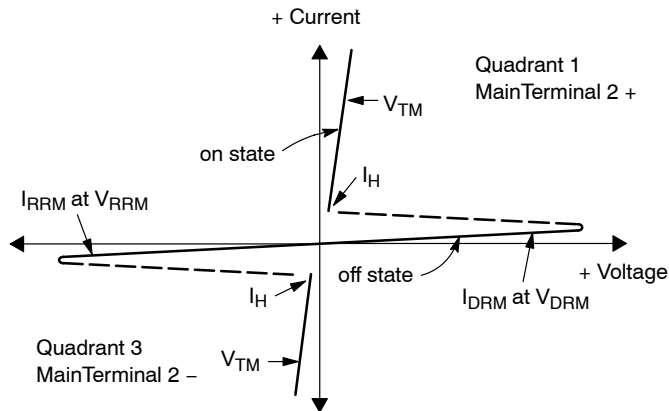
### Dynamic Characteristics

Rate of Change of Commutating Current ( $V_D = 400 \text{ V}, I_{TM} = .84 \text{ A}, \text{ Commutating } dv/dt = 1.5 \text{ V}/\mu s, \text{ Gate Open}, T_J = 110^{\circ}C, f = 250 \text{ Hz}, \text{ with Snubber}$ )	$di/dt(c)$	1.6	—	—	A/ms
Critical Rate of Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}, \text{ Exponential Waveform}, \text{ Gate Open}, T_J = 110^{\circ}C$ )	$dv/dt$	20	60	—	V/ $\mu s$
Repetitive Critical Rate of Rise of On-State Current Pulse Width = 20 $\mu s$ , $IPK_{max} = 15 \text{ A}, diG/dt = 1 \text{ A}/\mu s, f = 60 \text{ Hz}$	$di/dt$	—	—	10	A/ $\mu s$

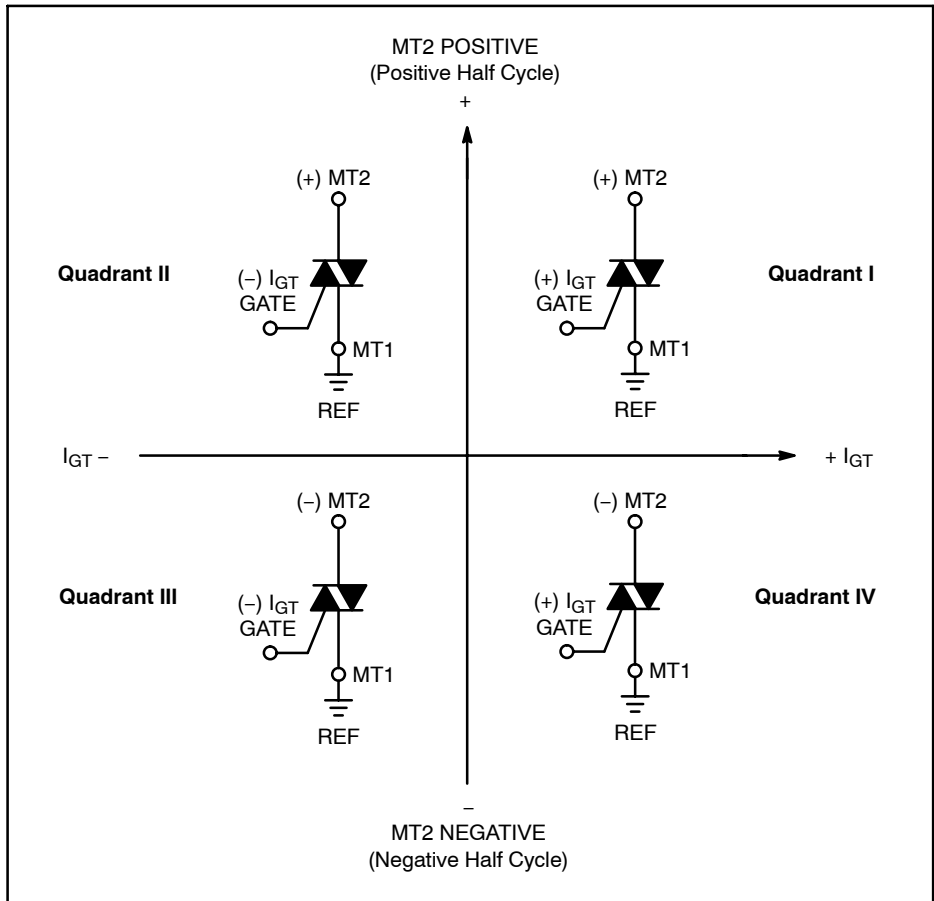
# MAC997 Series

## Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current



### Quadrant Definitions for a Triac



All polarities are referenced to MT1.  
 With in-phase signals (using standard AC lines) quadrants I and III are used.

# MAC997 Series

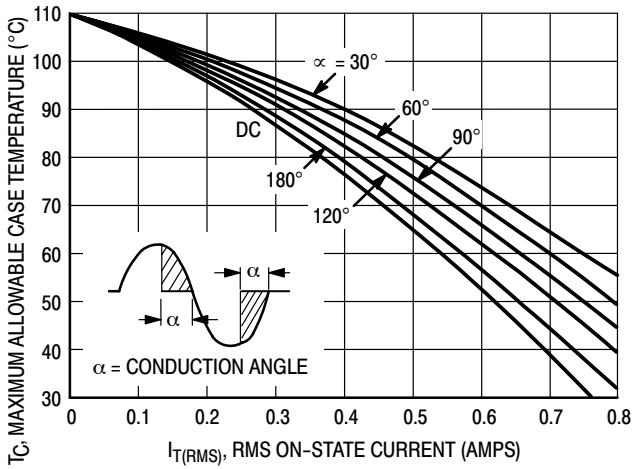


Figure 1. RMS Current Derating

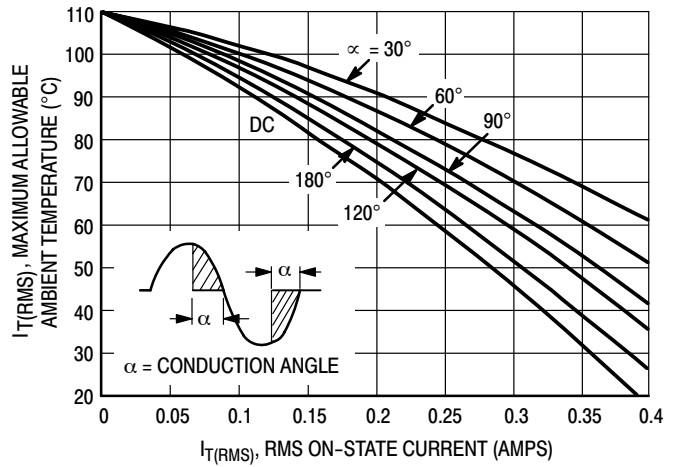


Figure 2. RMS Current Derating

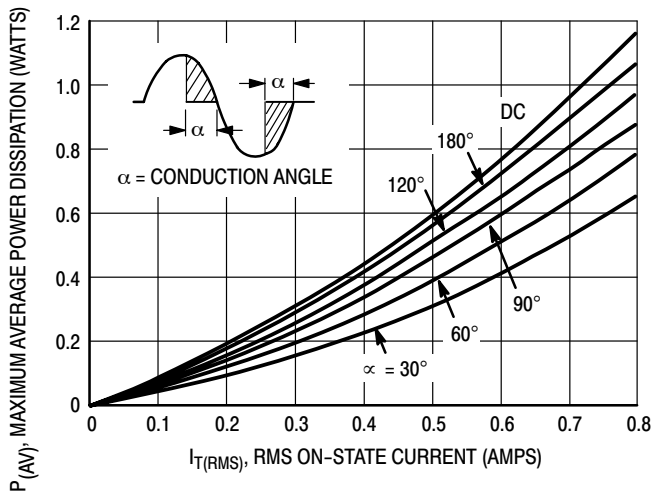


Figure 3. Power Dissipation

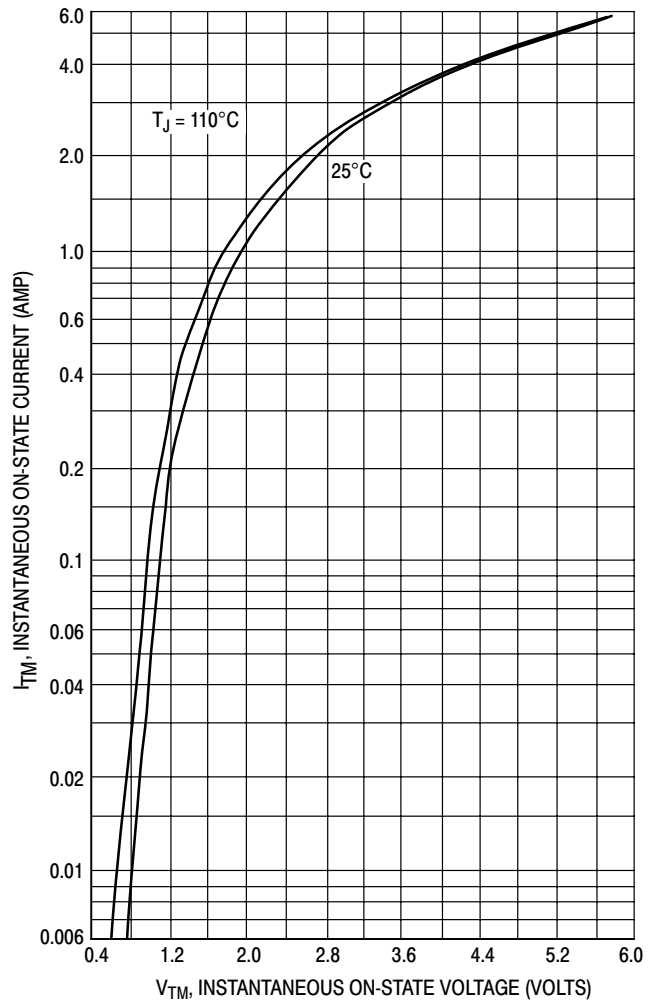


Figure 4. On-State Characteristics

# MAC997 Series

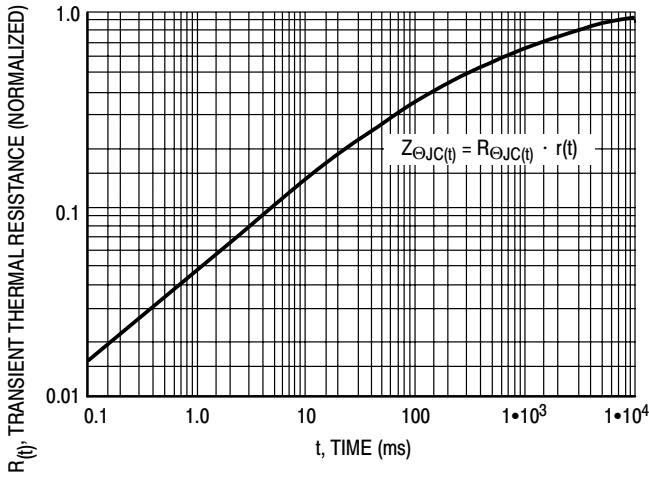


Figure 5. Transient Thermal Response

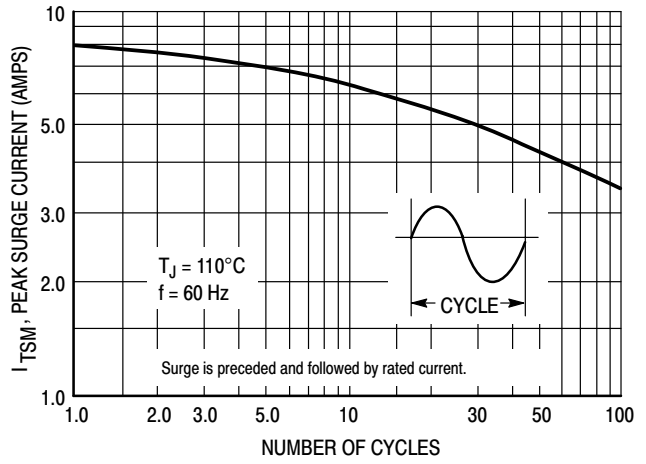


Figure 6. Maximum Allowable Surge Current

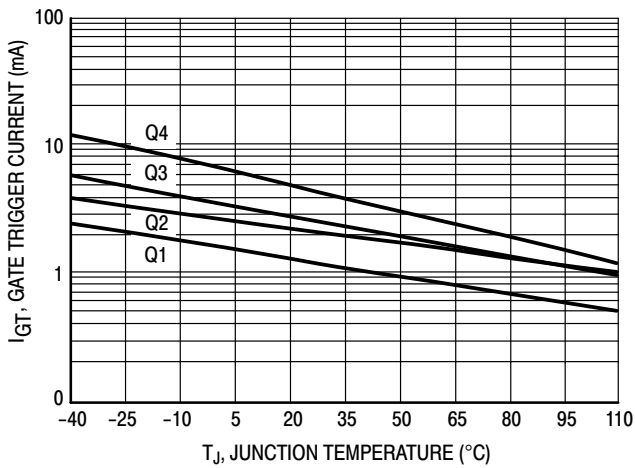


Figure 7. Typical Gate Trigger Current versus Junction Temperature

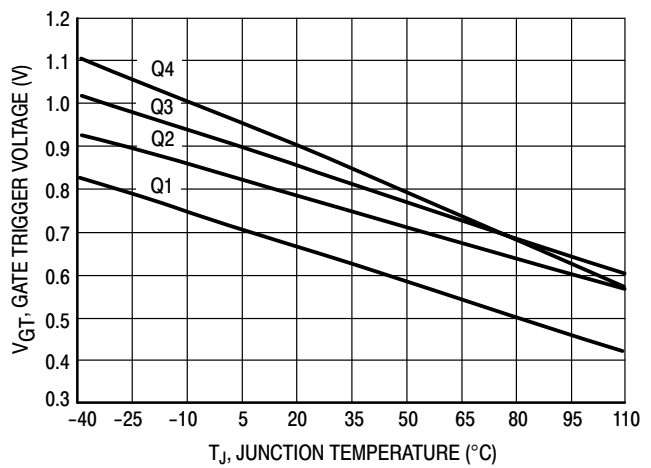


Figure 8. Typical Gate Trigger Voltage versus Junction Temperature

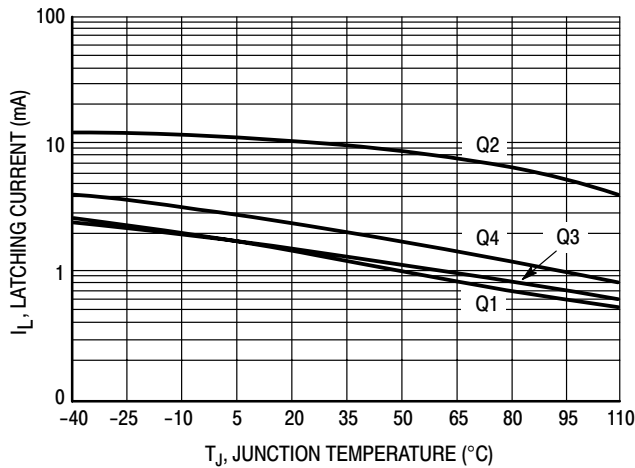


Figure 9. Typical Latching Current versus Junction Temperature

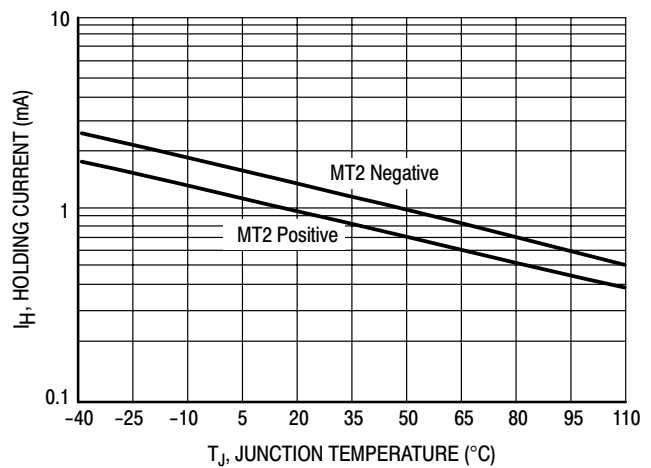
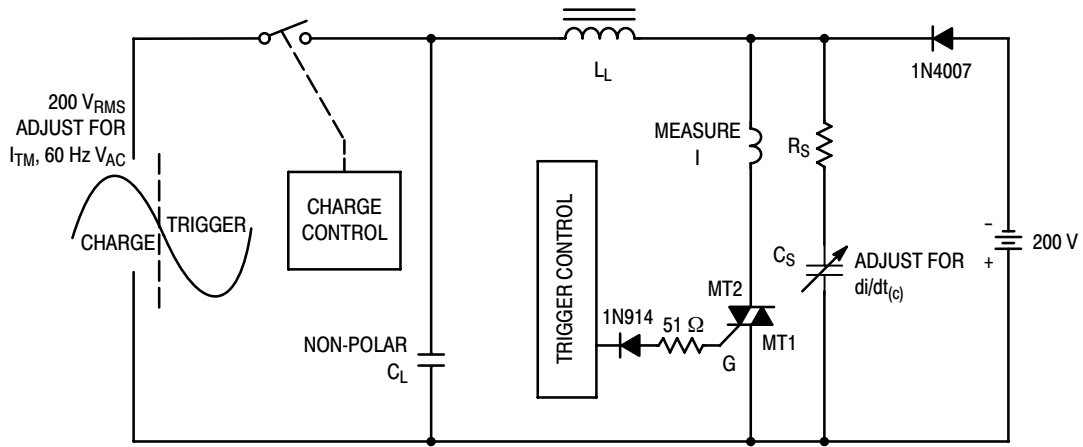


Figure 10. Typical Holding Current versus Junction Temperature

# MAC997 Series



Note: Component values are for verification of rated  $(di/dt)_c$ . See AN1048 for additional information.

**Figure 11. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current  $(di/dt)_c$**

# MAC997 Series

## TO-92 EIA RADIAL TAPE IN FAN FOLD BOX OR ON REEL

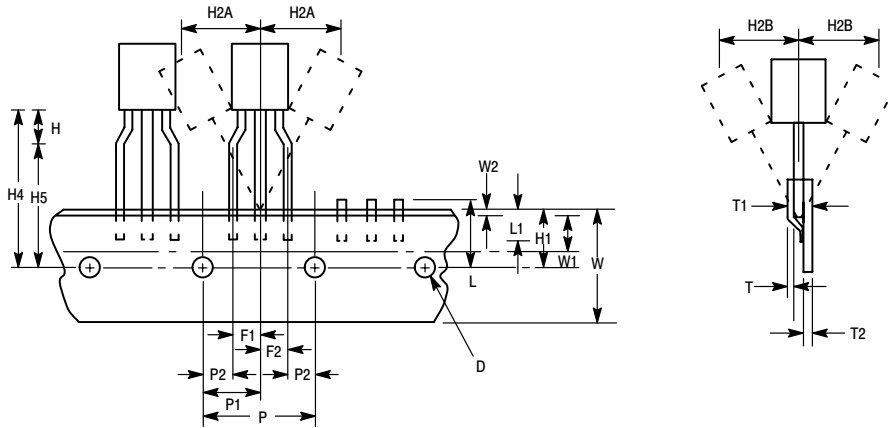


Figure 12. Device Positioning on Tape

Symbol	Item	Specification			
		Inches		Millimeter	
		Min	Max	Min	Max
D	Tape Feedhole Diameter	0.1496	0.1653	3.8	4.2
D2	Component Lead Thickness Dimension	0.015	0.020	0.38	0.51
F1, F2	Component Lead Pitch	0.0945	0.110	2.4	2.8
H	Bottom of Component to Seating Plane	.059	.156	1.5	4.0
H1	Feedhole Location	0.3346	0.3741	8.5	9.5
H2A	Deflection Left or Right	0	0.039	0	1.0
H2B	Deflection Front or Rear	0	0.051	0	1.0
H4	Feedhole to Bottom of Component	0.7086	0.768	18	19.5
H5	Feedhole to Seating Plane	0.610	0.649	15.5	16.5
L	Defective Unit Clipped Dimension	0.3346	0.433	8.5	11
L1	Lead Wire Enclosure	0.09842	—	2.5	—
P	Feedhole Pitch	0.4921	0.5079	12.5	12.9
P1	Feedhole Center to Center Lead	0.2342	0.2658	5.95	6.75
P2	First Lead Spacing Dimension	0.1397	0.1556	3.55	3.95
T	Adhesive Tape Thickness	0.06	0.08	0.15	0.20
T1	Overall Taped Package Thickness	—	0.0567	—	1.44
T2	Carrier Strip Thickness	0.014	0.027	0.35	0.65
W	Carrier Strip Width	0.6889	0.7481	17.5	19
W1	Adhesive Tape Width	0.2165	0.2841	5.5	6.3
W2	Adhesive Tape Position	.0059	0.01968	.15	0.5

NOTES:

1. Maximum alignment deviation between leads not to be greater than 0.2 mm.
2. Defective components shall be clipped from the carrier tape such that the remaining protrusion (L) does not exceed a maximum of 11 mm.
3. Component lead to tape adhesion must meet the pull test requirements.
4. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
5. Holddown tape not to extend beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
6. No more than 1 consecutive missing component is permitted.
7. A tape trailer and leader, having at least three feed holes is required before the first and after the last component.
8. Splices will not interfere with the sprocket feed holes.

## MAC997 Series

### ORDERING & SHIPPING INFORMATION: MAC97 Series packaging options, Device Suffix

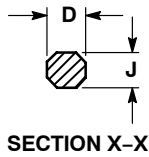
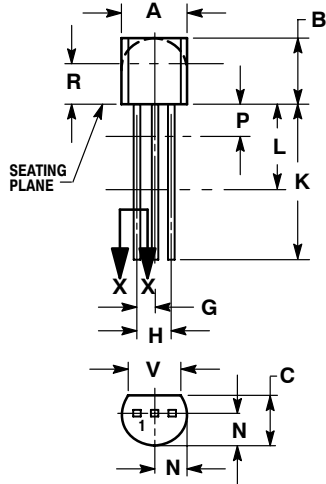
U.S.	Europe Equivalent	Shipping	Description of TO92 Tape Orientation
	MAC997A6RL1, A8RL1 MAC997B6RL1, B8RL1	Radial Tape and Reel (2K/Reel)	Flat side of TO92 and adhesive tape visible
MAC997A6,A8 MAC997B6,B8		Bulk in Box (5K/Box)	N/A, Bulk
MAC997A6RLRP, A8RLRP MAC997B6RLRP, B8RLRP		Radial Tape and Fan Fold Box (2K/Box)	Round side of TO92 and adhesive tape visible



# MAC997 Series

## PACKAGE DIMENSIONS

TO-92 (TO-226AA)  
CASE 029-11  
ISSUE AJ



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

**STYLE 12:**

- PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2

**Notes**

## Notes

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